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MOS FIELD EFFECT TRANSISTOR

2SK3307

(TO-3P)

SWITCHING N-CHANNEL POWER MOS FET

DESCRIPTION

The 2SK3307 is N-channel MOS Field Effect Transistor designed for high current switching applications.

FEATURES

• Super low on-state resistance:

 $R_{DS(on)1} = 9.5 \, m\Omega \, MAX. \, (V_{GS} = 10 \, V, \, I_{D} = 35 \, A)$

 $R_{DS(on)2} = 14 \text{ m}\Omega \text{ MAX}. \text{ (V}_{GS} = 4.0 \text{ V}, I_{D} = 35 \text{ A})$

- Low Ciss: Ciss = 4650 pF TYP.
- Built-in gate protection diode

ORDERING INFORMATION

PART NUMBER	PACKAGE
2SK3307	TO-3P

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage	VDSS	60	V
Gate to Source Voltage	$V_{GSS(AC)}$	±20	V
Drain Current (DC)	I _{D(DC)}	±70	Α
Drain Current (pulse) Note1	D(pulse)	±280	Α
Total Power Dissipation (Tc = 25°C)	P _{T1}	120	W
Total Power Dissipation (T _A = 25°C)	P _{T2}	3.0	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	-55 to +150	°C
Single Avalanche Current Note2	las	45	Α
Single Avalanche Energy Note2	Eas	202	mJ

Notes 1. PW \leq 10 μ s, Duty cycle \leq 1%

2. Starting T_{ch} = 25°C, R_G = 25 Ω , V_{GS} = 20 \rightarrow 0 V

THERMAL RESISTANCE

Channel to Case	Rth(ch-C)	1.04	°C/W
Channel to Ambient	Rth(ch-A)	41.7	°C/W

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Date Published
Printed in Japan

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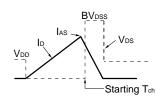


ELECTRICAL CHARACTERISTICS (TA = 25°C)

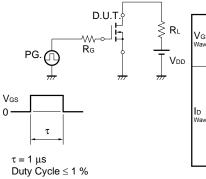
	1					
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	Inss	V _{DS} = 60 V, V _{GS} = 0 V			10	μΑ
Gate Leakage Current	Igss	V _{GS} = ±20 V, V _{DS} = 0 V			±10	μΑ
Gate Cut-off Voltage	V _{GS(off)}	V _{DS} = 10 V, I _D = 1 mA	1.5	2.0	2.5	V
Forward Transfer Admittance	y fs	V _{DS} = 10 V, I _D = 35 A	30	47		S
Drain to Source On-state Resistance	R _{DS(on)1}	V _{GS} = 10 V, I _D = 35 A		7.5	9.5	$m\Omega$
	R _{DS(on)2}	V _{GS} = 4.0 V, I _D = 35 A		10.5	14	$m\Omega$
Input Capacitance	Ciss	V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz		4650		pF
Output Capacitance	Coss			780		pF
Reverse Transfer Capacitance	Crss			380		pF
Turn-on Delay Time	t _{d(on)}	ID = 35 A, VGS = 10 V, VDD = 30 V,		90		ns
Rise Time	tr	R _G = 10 Ω		1260		ns
Turn-off Delay Time	t _{d(off)}			270		ns
Fall Time	tf			370		ns
Total Gate Charge	QG	I _D = 70 A , V _{DD} = 48 V, V _{GS} = 10 V		90		nC
Gate to Source Charge	Qgs			14		nC
Gate to Drain Charge	Q _{GD}			24		nC
Body Diode Forward Voltage	V _{F(S-D)}	I _F = 70 A, V _{GS} = 0 V		1.0		V
Reverse Recovery Time	trr	I _F = 70 A, V _{GS} = 0 V,		60		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/μs		110		nC

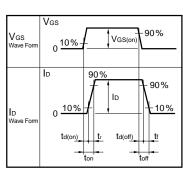
TEST CIRCUIT 1 AVALANCHE CAPABILITY

$\begin{array}{c} \text{D.U.T.} \\ \text{Rg} = 25 \Omega \\ \text{Vgs} = 20 \rightarrow 0 \text{V} \end{array} \begin{array}{c} \text{PG.} \\ \text{$\stackrel{>}{\sim}$} 50 \Omega \\ \text{$\stackrel{>}{\sim}$} \end{array} \begin{array}{c} \text{Voc} \\ \text{$\stackrel{>}{\sim}$} \end{array}$



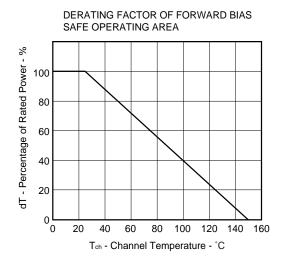
TEST CIRCUIT 2 SWITCHING TIME

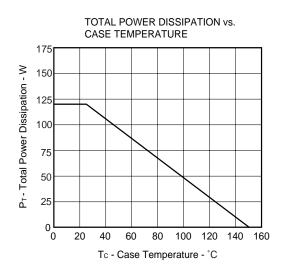




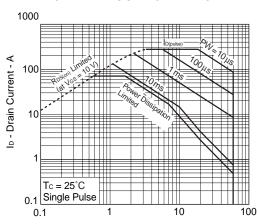
TEST CIRCUIT 3 GATE CHARGE

TYPICAL CHARACTERISTICS (TA = 25°C)



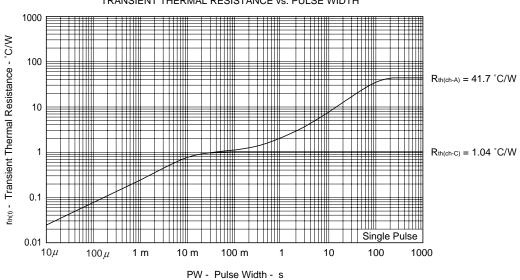


FORWARD BIAS SAFE OPERATING AREA



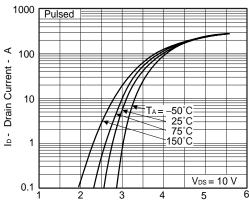
 $V_{\text{\scriptsize DS}}$ - Drain to Source Voltage - V

TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

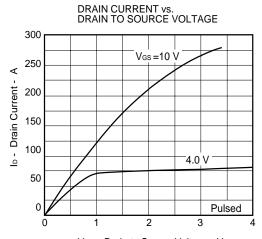


3

FORWARD TRANSFER CHARACTERISTICS

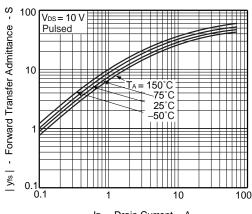


V_{GS} - Gate to Source Voltage - V

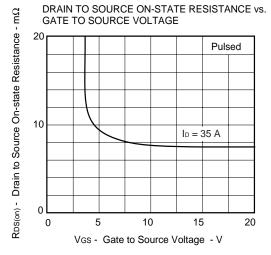


V_{DS} - Drain to Source Voltage - V

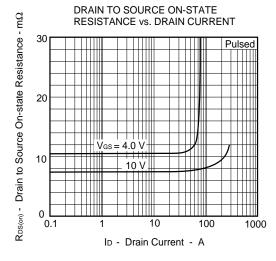
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



ID - Drain Current - A



GATE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



0

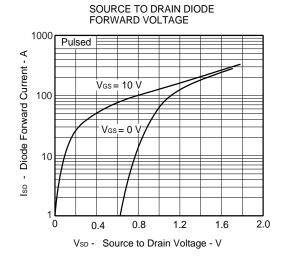
-50

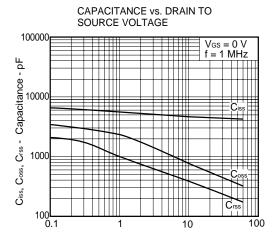
Сm CHANNEL TEMPERATURE RDS(on) - Drain to Source On-state Resistance -Pulsed 20 $V_{GS} = 4.0 V$ 15 10 10 V 5 ID = 35 A

Tch - Channel Temperature - °C

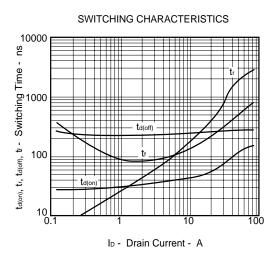
150

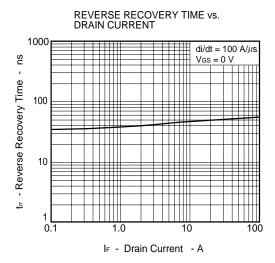
DRAIN TO SOURCE ON-STATE RESISTANCE vs.

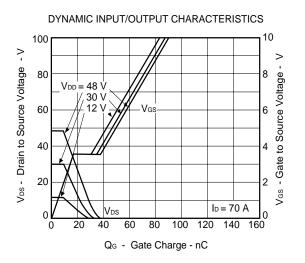




V_{DS} - Drain to Source Voltage - V

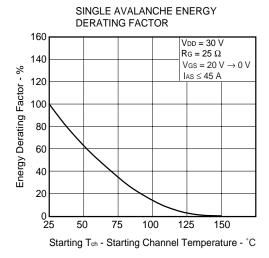






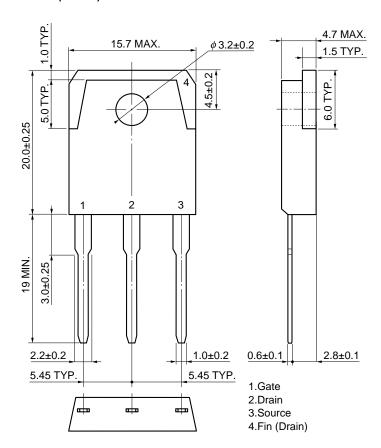
SINGLE AVALANCHE CURRENT vs. INDUCTIVE LOAD 1000 V 100 IAS = 45AVDD = 30VRG = 25Ω VGS = $20V \rightarrow 0V$ 10 μ 10 μ 10 μ 10 μ

L - Inductive Load - H

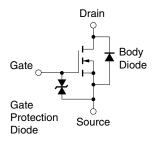


PACKAGE DRAWING (Unit: mm)

<R> TO-3P (MP-88)



EQUIVALENT CIRCUIT



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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